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FDP8441 N-Channel PowerTrench[®] MOSFET

FDP8441

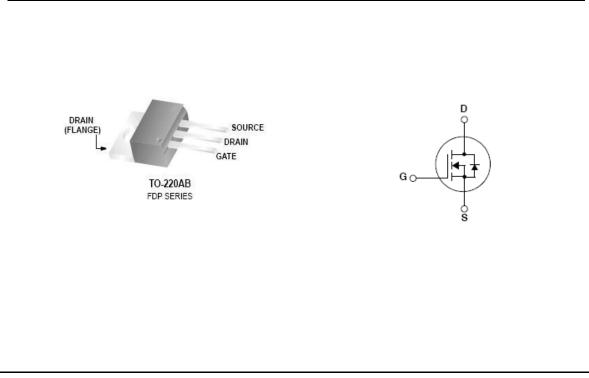
N-Channel PowerTrench[®] MOSFET 40V, 80A, 2.7m Ω

Features

- Typ $r_{DS(on)} = 2.1m\Omega$ at $V_{GS} = 10V$, $I_D = 80A$
- Typ Q_{g(10)} = 215nC at V_{GS} = 10V
- Low Miller Charge
- Low Q_{rr} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- RoHS Compliant

Applications

- Solenoid and Motor Drivers
- Distributed Power Architectures and VRMs



Symbol	Parameter		Ratings	Units
V _{DS}	Drain to Source Voltage		40	V
V _{GS}	Gate to Source Voltage		±20	V
	Drain Current Continuous (T _C < 160°C, V _{GS} = 10V)		80	
I _D	Continuous (T_{amb} = 25°C, V_{GS} = 10V, with $R_{\theta JA}$ = 62°C/W)		23	Α
	Pulsed		See Figure 4	
E _{AS}	Single Pulse Avalanche Energy (N	ote 1)	947	mJ
П	Power dissipation		300	W
P _D	Derate above 25°C		2	W/ºC
T _J , T _{STG}	Operating and Storage Temperature		-55 to 175	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance Junction to Case		0.5	°C/W
$R_{\theta JA}$	Thermal Resistance Junction to Ambient	(Note 2)	62	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDP8441	FDP8441	TO-220AB	Tube	N/A	50 units

Electrical Characteristics $T_J = 25^{\circ}C$ unless otherwise noted

Symbol Parameter Test Conditions Min Typ Max Units	1						
	Symbol	Parameter	Test Conditions	Min	Тур	Max	Units

Off Characteristics

B _{VDSS}	Drain to Source Breakdown Voltage	I _D = 250μA, V _C	_{as} = 0V	40	-	-	V
1	Zero Gate Voltage Drain Current	$V_{DS} = 32V$		-	-	1	uА
IDSS Zero Gate Voltage Drain Current	$V_{GS} = 0V$	$T_J = 150^{\circ}C$	-	-	250	μΑ	
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20V$		-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	2	2.8	4	V
		I _D = 80A, V _{GS} = 10V	-	2.1	2.7	
r _{DS(on)}	Drain to Source On Resistance	$I_{\rm D} = 80 \text{A}, \text{ V}_{\rm GS} = 10 \text{V}, \\ T_{\rm J} = 175^{\circ}\text{C}$	-	3.6	4.7	mΩ

Dynamic Characteristics

Ciss	Input Capacitance	— V _{DS} = 25V, V _{GS} = 0V, f = 1MHz		-	15000	-	pF
C _{oss}	Output Capacitance			-	1250	-	pF
C _{rss}	Reverse Transfer Capacitance			-	685	-	pF
R _G	Gate Resistance	V _{GS} = 0.5V, f = 1	MHz	-	1.1	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V		-	215	280	nC
Q _{g(TH)}	Threshold Gate Charge	$V_{GS} = 0$ to 2V	V _{DD} = 20V	-	29	38	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 35A	-	60	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau		l _g = 1mA	-	32	-	nC
Q _{gd}	Gate to Drain "Miller" Charge		-	-	49	-	nC

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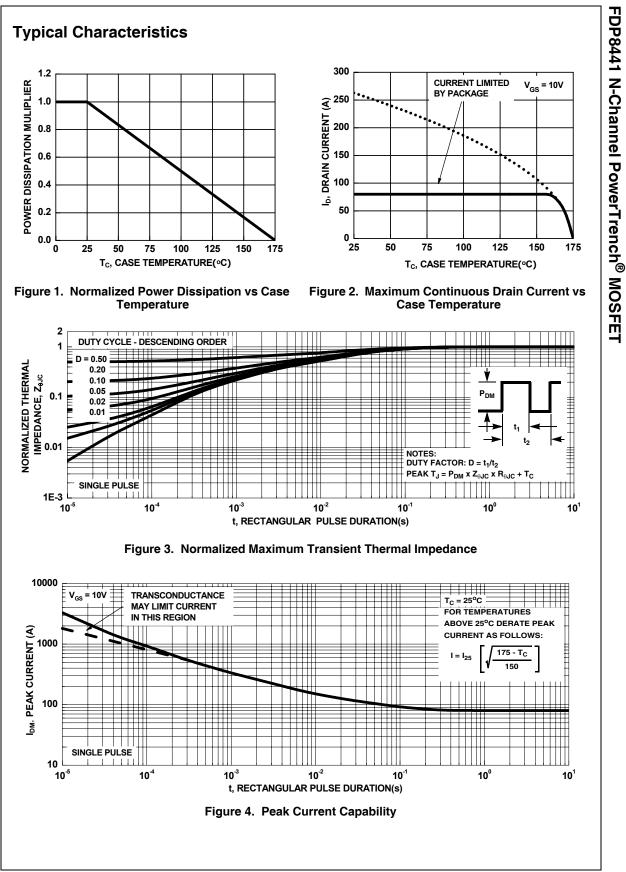
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switching	g Characteristics					
t _(on)	Turn-On Time		-	-	77	ns
d(on)	Turn-On Delay Time		-	23	-	ns
r	Turn-On Rise Time	V _{DD} = 20V, I _D = 35A	-	24	-	ns
d(off)	Turn-Off Delay Time	V_{DD} = 20V, I _D = 35A V _{GS} = 10V, R _{GS} = 1.5Ω	-	75	-	ns
f	Turn-Off Fall Time		-	17.9	-	ns
toff	Turn-Off Time		-	-	147	ns

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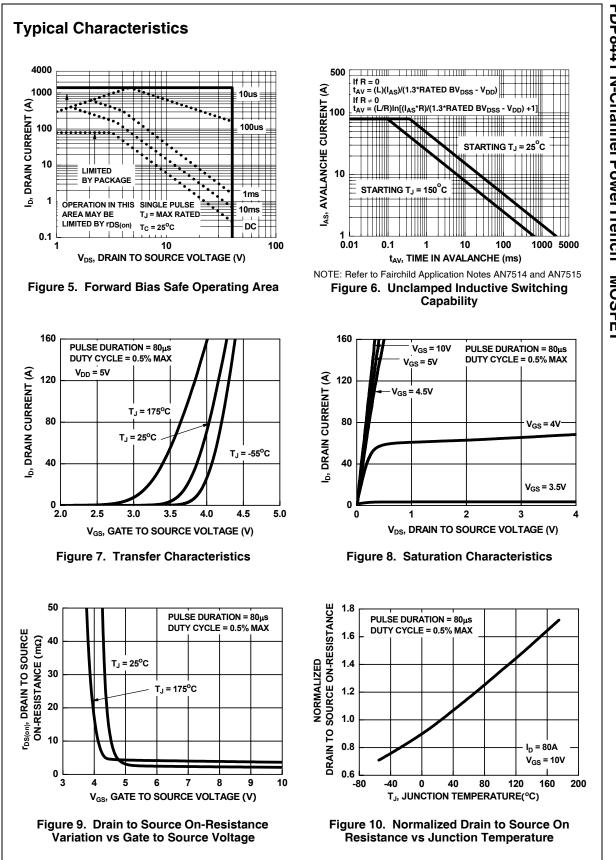
V	Source to Drain Diode Voltage	I _{SD} = 35A	-	0.8	1.25	V
V _{SD} Source to Drain Diode Voltage	I _{SD} = 15A	-	0.8	1.0	V	
t _{rr}	Reverse Recovery Time	$I_{F} = 35A, di/dt = 100A/\mu s$	-	52	68	ns
Q _{rr}	Reverse Recovery Charge	I _F = 35A, di/dt = 100A/μs	-	76	99	nC

Notes: 1: Starting $T_J = 25^{\circ}$ C, L = 0.46mH, I_{AS} = 64A. 2: Pulse width = 100s.

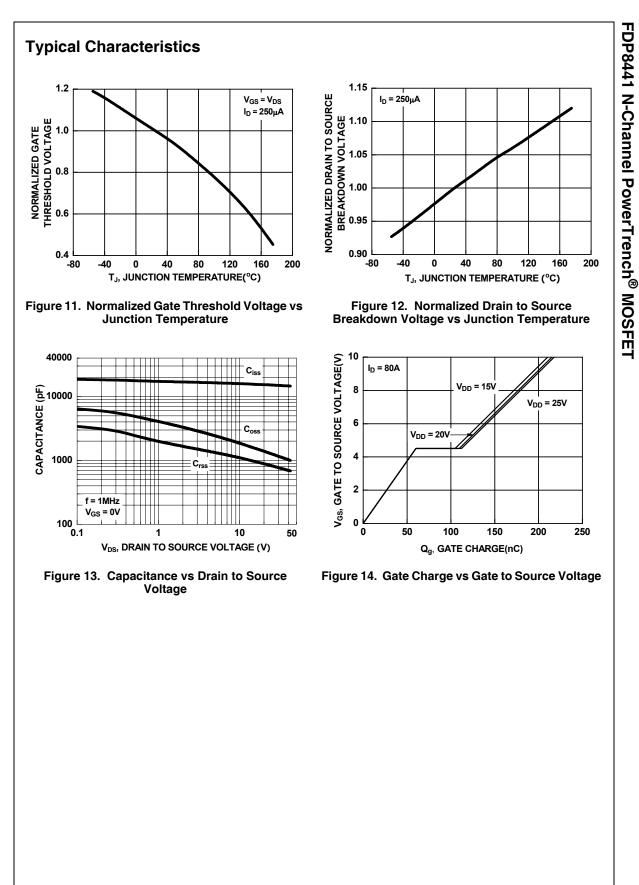
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FDP8441 Rev. C0



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